POWER OF ATTORNEY BY ASSIGNEE OF ENTIRE INTEREST

Revocation of Power of Attorney with New Power of Attorney

NANYA TECHNOLOGY CORP., as assignee of record of the entire right, title and interest in each of the patent application(s) or patent(s) listed in the table of Attachment A, hereby revoke all powers of attorney previously given in each of the listed patent application(s) or patent(s) and appoint all practitioners associated with the Customer Number:

27765

as the attorney(s) or agent(s) to represent the undersigned before the United States Patent and Trademark Office (USPTO) in connection with any and all of the listed patent application(s) and patent(s).

Please recognize or change the correspondence address for the above-identified application to the address associated with the above-mentioned Customer Number.

Statement under 37 CFR 3.73(b)

I hereby state that, as required by 37 CFR 3.73(b)(1)(i), the documentary evidence of the chain of title from the original owner to the assignee was, or concurrently is being, submitted for recordation pursuant to 37 CFR 3.11. The chain of title is indicated in the table of Attachment A.

Pursuant to 37 CFR 3.71, I hereby state the prosecution of the listed application(s) or reexamination of the listed patent(s) is to be conducted to the exclusion of both the inventor(s) and previous assignee(s).

The undersigned is authorized to act on behalf of the assignee.

Jih Li

Signature

Name

Title

President

Jih Lien

Date Sept. 8, 2009

Attachment A

					Chain of Title	
Appl. No.	Filing Date	Title	, o	from	q	Reel/Frame No.
			<u> </u>	LANE, RICHARD THAKUR, RANDHIR PS	MICRON TECHNOLOGY, INC.	010390/0415
09/135,474	09/135,474 1998/08/17	PROCESS FOR MAKING AN ISOLATION STRUCTURE	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			Н	LANE, RICHARD THAKUR, RANDHIR PS	MICRON TECHNOLOGY, INC.	010390/0415
09/911,580	09/911,580 2001/07/24	ISOLATION STRUCTURE AND PROCESS THEREFOR	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
09/291,127	09/291,127 1999/04/13	ELECTRODE AND CAPACITOR STRUCTURE FOR A	1	AGARWAL, VISHNU K.	MICRON TECHNOLOGY, INC.	009897/0668

		SEMICONDUCTOR DEVICE AND ASSOCIATED METHODS OF MANUFACTURE	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			F-1	AGARWAL, VISHNU K.	MICRON TECHNOLOGY, INC.	011193/0819
09/654,997 2000/08/31	0/08/31	CAPACITOR AND ELECTRODE STRUCTURES FOR A SEMICONDUCTOR DEVICE	7	Містоп Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			1	FARRAR, PAUL A.	MICRON TECHNOLOGY, INC.	009376/0238
09/128,859 1998/08/04	8/08/04	COPPER METALLURGY IN INTEGRATED CIRCUITS	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			Н	FARRAR, PAUL A.	MICRON TECHNOLOGY, INC.	009376/0238
09/946,055 2001/09/04	1/09/04	COPPER METALLURGY IN INTEGRATED CIRCUITS	2	Містоп Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
09/033,064 1998/02/28	18/02/28	METHOD OF FORMING HIGH-K OXYGEN-CONTAINING DIELECTRIC LAYERS INCLUDING MANUFACTURE OF CAPACITORS AND DRAM CELLS	H	AL-SHAREEF, HUSAM N. DEBOER, SCOTT JEFFREY THAKUR, RANDHIR P. S.	MICRON TECHNOLOGY, INC.	009013/0121

			2	THAKUR, RANDHIR P.S.	MICRON TECHNOLOGY, INC.	009261/0355
			က	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
				FORBES, LEONARD NOBLE, WENDELL P.	MICRON TECHNOLOGY, INC.	010202/0223
7007000700	MOSFET TECHNOLOGY FOR PROGRAMMABLE	OR PROGRAMMABLE	 -	CLOUD, EUGENE H.		
09/383,804 1999/08/26	ADDRESS DECODE AND CORRECTION		7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
				FORBES, LEONARD		-
			F-4	NOBLE, WENDELL P.	MICRON TECHNOLOGY, INC.	010202/0223
00, 100, 00	PR.	I TECHNOLOGY AND		CLOUD, EUGENE H.		
09/924,639/2001/08/08	ORRECTION CORRECTION		7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

PROGRAMMABLE MEMORY CELL USING CHARGE	ם	1 HARGE	NOBLE, WENDELL P. CLOUD, EUGENE H.	MICRON TECHNOLOGY, INC.	010202/0223
TRAPPING IN A GATE OXIDE		- 7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		Ε'	PING, ER-XUAN HUANG, YING	MICRON TECHNOLOGY, INC.	010219/0912
09/389,294 1999/09/02 REDUCTION OF SHORTS AMONG ELECTRICAL CELLS FORMED ON A SEMICONDUCTOR SUBSTRATE	ICAI STR	ATE 2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
OTP CTITT A NID METHOD FOR MEMORY DEVICE WITH	VICE	1 1	CASPER, STEPHEN L. PINNEY, DAVID KEETH, BRENT	MICRON TECHNOLOGY, INC.	008679/0825
DEFECT CURRENT ISOLATION		2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

CIRCUIT AND METHOD FOR MEMORY DEVICE WITH
DEFECT CURRENT ISOLATION
CIRCUIT AND METHOD FOR MEMORY DEVICE WITH
DEFECT CURRENT ISOLATION
Circuit and method for memory device with defect current
- 7

			SHIRLEY, BRIAN M.	MICRON TECHNOLOGY, INC.	009012/0671
09/026,603 1998/02/20	TWISTED GLOBAL COLUMN DECODER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		F-4	SHIRLEY, BRIAN M.	MICRON TECHNOLOGY, INC.	009012/0671
09/362,076 1999/07/27	TWISTED GLOBAL COLUMN DECODER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		<u>~</u>	SHIRLEY, BRIAN M.	MICRON TECHNOLOGY, INC.	009012/0671
09/583,439 2000/05/31	TWISTED GLOBAL COLUMN DECODER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		F-4	MORGAN, DONALD M.	MICRON TECHNOLOGY, INC.	011385/0718
09/651,639 2000/08/30	0 MID ARRAY ISOLATE CIRCUIT LAYOUT	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
10/229,555 2002/08/28	28 Mid-array isolate circuit layout and method	₩.	MORGAN, DONALD M.	MICRON TECHNOLOGY, INC.	011385/0718
		-			

WALLER, WILLIAM K.
FARNWORTH, WARREN M.
SELF-TEST OF A MEMORY DEVICE CLOUD, EUGENE H.
2 Micron Technology, Inc.
MANNING, TROY A.
METHOD AND APPARATUS FOR MEMORY ARRAY OOMPRESSED DATA TESTING
)
VOSHELL, THOMAS W.

			7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			-	SHER, JOSEPH C. BLODGETT, GREG A.	MICRON TECHNOLOGY, INC.	008657/0259
08/906,754 1997/08/05	97/08/05	MEMORY REPAIR	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
				MERRIT, TODD A. VAN HEEL, NICK	MICRON TECHNOLOGY, INC.	010548/0094
09/352/352/199	99/07/13	09/352 352 1999/07/13 TEST AND OBSERVE MODE FOR EMBEDDED MEMORY	2	HEEL, NICK VAN	MICRON TECHNOLOGY, INC.	011803/0738
			т	Micron Technology, Inc.	NANYA TECHINOLOGY CORP.	attached and concurrently submitted for recordation
			H	HU, YONGJUN	Micron Technology, Inc.	008777/0373
10/003,522 2001/10/31	01/10/31	ANTIREFLECTIVE COATING LAYER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

				HU, YONGJUN	Micron Technology, Inc.	008777/0373
09/631,264	09/631,264 2000/08/02	PHOTOLITHOGRAPHY METHOD USING AN ANTIREFLECTIVE COATING	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
				HU, YONGJUN	Micron Technology, Inc.	008777/0373
09/476,558	09/476,558 2000/01/03	ANTIREFLECTIVE COATING LAYER	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			,	JOO, YANGSUNG	MICRON TECHNOLOGY, INC.	013267/0389
10/233,997	10/233,997 2002/08/29	DRIVING A DRAM SENSE AMPLIFIER HAVING LOW THRESHOLD VOLTAGE PMOS TRANSISTORS	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			H	JOO, YANGSUNG	MICRON TECHNOLOGY, INC.	013267/0389
10/783,976	10/783,976 2004/02/20	DRIVING A DRAM SENSE AMPLIFIER HAVING LOW THRESHOLD VOLTAGE PMOS TRANSISTORS	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
10/696,971	10/696,971 2003/10/30	Data compression read mode for memory testing	F-1	NASO, GIOVANNI	MICRON TECHNOLOGY, INC.	014659/0206

NANYA TECHNOLOGY CORP. submitted for recordation	MICRON TECHNOLOGY, INC. 011693/0081	NANYA TECHNOLOGY CORP. submitted for recordation	MICRON TECHNOLOGY, INC. 013251/0264	NANYA TECHNOLOGY CORP. submitted for recordation	MICRON TECHNOLOGY, INC. 013251/0264	
	-					
Micron Technology, Inc.	MERRITT, TODD A. THOMPSON, J. WAYNE	Micron Technology, Inc.	MARR, KENNETH W. PORTER, JOHN D.	Micron Technology, Inc.	MARR, KENNETH W. PORTER, JOHN D.	
2		Metal wiring pattern for memory devices	1	10/230,928 2002/08/29 GATE DIELECTRIC ANTIFUSE CIRCUIT TO PROTECT A HIGH-VOLTAGE TRANSISTOR 2		
		09/805,913 2001/03/15		10/230,928 2002/08/29		_

			KIRSCH, HOWARD		
		-	KIM, TAE HYOUNG	MICRON TECHNOLOGY, INC.	013255/0858
			INGALLS, CHARLES L.		
10/231,389 2002/08/29	WORD LINE DRIVER FOR NEGALIVE VOLIAGE	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		H	KIM, TAE HYOUNG VO, HUY	MICRON TECHNOLOGY, INC.	013543/0899
	SYSTEM AND METHOD FOR NEGATIVE WORD LINE		BLODGETT, GREG		
10/232,953 2002/08/29		CI	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			KIM, TAE HYOUNG		
		Н	VO, HUY BLODGETT, GREG	MICRON TECHNOLOGY, INC.	013543/0899
10/860,881 2004/06/03	SYSTEM AND METHOD FOR NEGATIVE WORD LINE DRIVER CIRCUIT	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

				V TIVE LATER		
			H	AHIN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
08/950,319 1997/10/14	997/10/14	POROUS SILICON OXYCARBIDE INTEGRATED CIRCUIT INSULATOR	74	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			1	AHN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
09/517,029 2000/03/02	.000/03/02	Porous silicon oxycarbide integrated circuit insulator	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			μ.	AHN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
09/909,532 2001/07/20	.001/07/20	POROUS SILICON OXYCARBIDE INTEGRATED CIRCUIT INSULATOR	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
			1	AHN, KIE Y. FORBES, LEONARD	MICRON TECHNOLOGY, INC.	008784/0988
10/083,051 2002/02/26	.002/02/26	POROUS SILICON OXYCARBIDE INTEGRATED CIRCUIT INSULATOR	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

006665/0347	attached	attached and concurrently submitted for recordation	007460/0835	009187/0739	attached and concurrently submitted for recordation	007811/0575	008235/0516
MICRON SEMICONDUCTOR, INC.	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	MICRON SEMICONDUCTOR, INC. MICRON TECHNOLOGY INC.		NANYA TECHNOLOGY CORP.	MICRON TECHNOLOGY, INC.	MICRON TECHNOLOGY, INC., A DELAWARE CORP
THAKUR, RANDHIR P.S. GONZALEZ, FERNANDO	MICRON SEMICONDUCTOR, INC.	Micron Technology, Inc.	THAKUR, RANDHIR P.S. MICRON SEMICONDUCTOR, INC.		Micron Technology, Inc.	THAKUR, RANDHIR P.S. GONZALEZ, FERNANDO	THAKUR, RANDHIR P.S. GONZALEZ, FERNANDO
F-1		ဇ	7 7		8	1	2
	METHOD FOR OPTIMIZING THERMAL BUDGETS IN FABRICATING SEMICONDUCTORS			METHOD FOR OPTIMIZING THERMAL BUDGETS IN		METHOD FOR OPTIMIZING THERMAL BUDGETS IN FABRICATING SEMICONDUCTORS	
1993/08/06		1995/04/25			08/559,511 1995/11/15		
08/102,908 1993/08/06		08/427,941 1995/04/25			08/559,511		

		м	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		7	KIRSCH, HOWARD C.	MICRON TECHNOLOGY, INC.	013256/0297
10/231,626 2002/08/2	10/231,626 2002/08/29 REFRESH POWER BY REDUCING ACCESS TRANSISTOR SUB THRESHOLD LEAKAGE	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		H	KIRSCH, HOWARD C.	MICRON TECHNOLOGY, INC.	013256/0297
11/040,959 2005/01/1	METHOD AND CIRCUIT FOR REDUCING DRAM 11/040,959 2005/01/19 REFRESH POWER BY REDUCING ACCESS TRANSISTOR SUB THRESHOLD LEAKAGE	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
		H	JOO, YANGSUNG PINNEY, DAVID L. BROWN, JASON	MICRON TECHNOLOGY, INC.	015741/0152
10/926,357 2004/08/26	16 DUAL STAGE DRAM MEMORY EQUALIZATION	2	Micron Technology, Inc.	NANYA TECHINOLOGY CORP.	attached and concurrently submitted for recordation
08/666,617 1996/06/18	8 Voltage generator for antifuse programming		SHER, JOSEPH C.	MICRON TECHNOLOGY, INC.	008063/0562

	7	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation
	1	FORBES, LEONARD	MICRON TECHNOLOGY, INC.	011067/0527
Clock-delayed pseudo-nmos domino logic	2	Micron Technology, Inc.	NANYA TECHNOLOGY CORP.	attached and concurrently submitted for recordation

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

ASSIGNMENT

WHEREAS, Micron Technology, Inc., a corporation organized and existing under the laws of Delaware ("ASSIGNOR"), owns certain patent applications and/or registrations, as set forth in <u>Attachment 1</u> attached hereto and incorporated herein by this reference ("PATENTS"); and

WHEREAS, Nanya Technology Corporation (南亞科技股份有限公司), a company incorporated under the laws of the Republic of China ("ASSIGNEE"), desires to acquire all of the right, title and interest of ASSIGNOR in, to and under the PATENTS;

WHEREAS, ASSIGNOR and ASSIGNEE have entered into a certain Patent Assignment Agreement, dated June 6, 2008 assigning, all of ASSIGNOR's right, title and interest in and to the PATENTS from ASSIGNOR to ASSIGNEE upon the terms and subject to the conditions set for the in the Patent Assignment Agreement;

Now, Therefore, in consideration of the sum of One Dollar (\$1.00) and other good and valuable consideration from ASSIGNEE to ASSIGNOR, the receipt and sufficiency of which hereby is acknowledged, ASSIGNOR does hereby sell, assign, transfer and convey unto ASSIGNEE all of ASSIGNOR's right, title and interest in and to the PATENTS, including all rights to causes of action and remedies related thereto (including, the right to sue for past, present or future infringement related to the foregoing) upon the terms and subject to the conditions set forth in the Patent Assignment Agreement;

IN WITNESS WHEREOF, ASSIGNOR has caused this Assignment to be duly executed by an authorized officer on this 5th day of June, 2009.

By: Roderic W. Lewis

Title: V. F. of Legal Affairs

STATE OF Tours

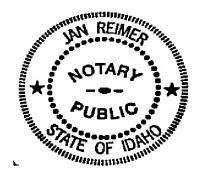
) ss.

COUNTY OF Ada)

On Leve 5 , 2008, before me, the undersigned notary public in and for said County and State, personally appeared Roderic W. Lewis , personally known to me to be the person(s) whose name is subscribed to the above instrument and acknowledged to me that he executed the same in his authorized capacity and that, by his signature on the instrument, the entity upon behalf of which the he acted executed the instrument.

My commission expires on

WITNESS my hand and official seal.



Micron NTC '

ATTACHMENT 1 PATENTS

SERIAL NUMBER OR	FILING DATE
REGISTRATION NUMBER	
6265282	8/17/1998
6414364	7/24/2001
6218256	4/13/1999
6346746	8/31/2000
6284656	8/4/1998
6614099	9/4/2001
6162744	2/28/1998
6521958	8/26/1999
6700821	8/8/2001
6909635	1/22/2004
6399983	9/2/1999
5896334	8/14/1997
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6154401	3/20/2000
5949698	2/20/1998
6111774	7/27/1999
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6574128	8/30/2000
6714434	8/28/2002
6301164	8/25/2000
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5935263	7/1/1997
6154851	8/5/1997
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6614085	10/31/2001
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7101738	8/31/2004
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6313518	3/2/2000

Micron NTC

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4/25/1995
11/15/1995
8/29/2002
1/19/2005
8/26/2004
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